

DFN1006-2L ESD 静电保护二极管

■Features 特点

Low Capacitance ESD Protection 低电容静电保护

- ±10kV Contact Discharge 接触放电

- ±15kV Air Discharge 空气放电

■Applications 应用

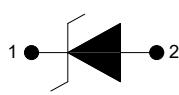
MP3 Players 播放器

Digital Cameras 数码相机

Notebooks & Handhelds 笔记本或手持机

Cellular handsets and accessories 蜂窝手机及附件

■Internal Schematic Diagram 内部结构



DFN1006-2L

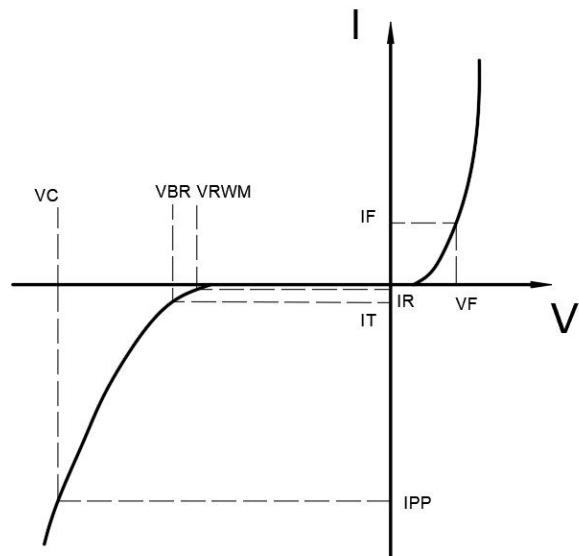
■Absolute Maximum Ratings 最大额定值

Characteristic 特性参数	Symbol 符号	Rating 额定值	Unit 单位
ESD (IEC61000-4-2 contact discharge) @25°C接触放电	V _{ESD}	±10	kV
ESD (IEC61000-4-2 air discharge) @25°C 空气放电	V _{ESD}	±15	kV
Peak Pulse Current @25°C峰值脉冲电流	I _{PP}	4	A
Peak Pulse Power @25°C峰值脉冲功率	P _{PK}	80	W
Lead Temperature 管脚温度	T _L	260	°C
Operating Temperature 工作温度	T _{op}	-40~85	°C
Junction Temperature 结温	T _J	125	°C
Storage Temperature 储存温度	T _{stg}	-55~150	°C

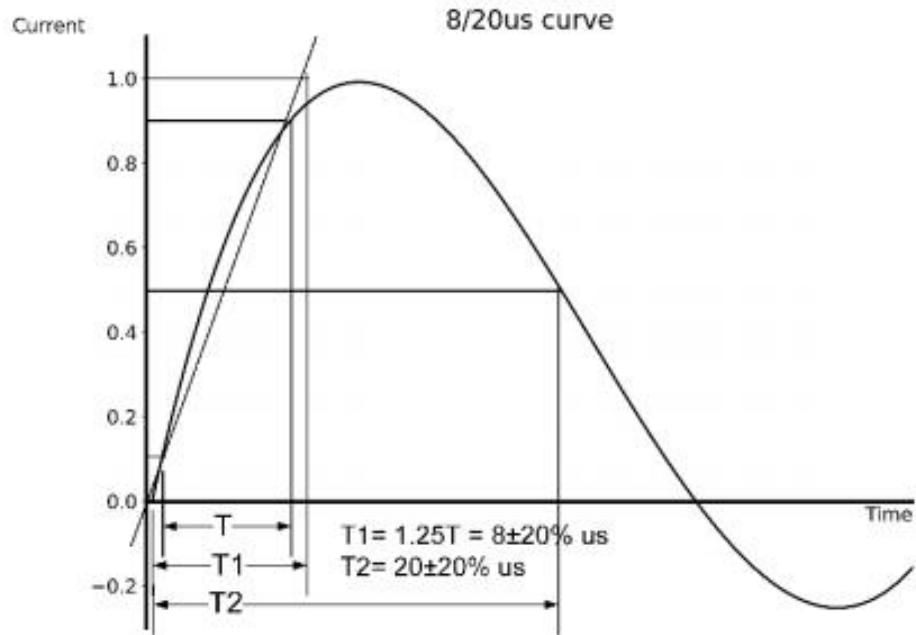
■ Electrical Characteristics 电特性(T_A=25°C unless otherwise noted 如无特殊说明，温度为 25°C)

Characteristic Parameters 特性参数	Symbol 符号	Min 最小值	Typ 典型值	Max 最大值	Unit 单位	Condition 条件
Reverse Stand-off Voltage 反向工作电压	V _{RWM}			5	V	
Reverse Breakdown Voltage 反向击穿电压	V _{BR}	6			V	I _T =1mA
Reverse Leakage Current 反向漏电流	I _R			1	μA	V _{RWM} =5V
Clamping Voltage 钳位电压	V _C		15		V	I _{PP} =1A,tp=8/20μs
Clamping Voltage 钳位电压	V _C		20		V	I _{PP} =4A,tp=8/20μs
Diode Capacitance 二极管电容	C _D		0.6		pF	V _R =0V,f=1MHz

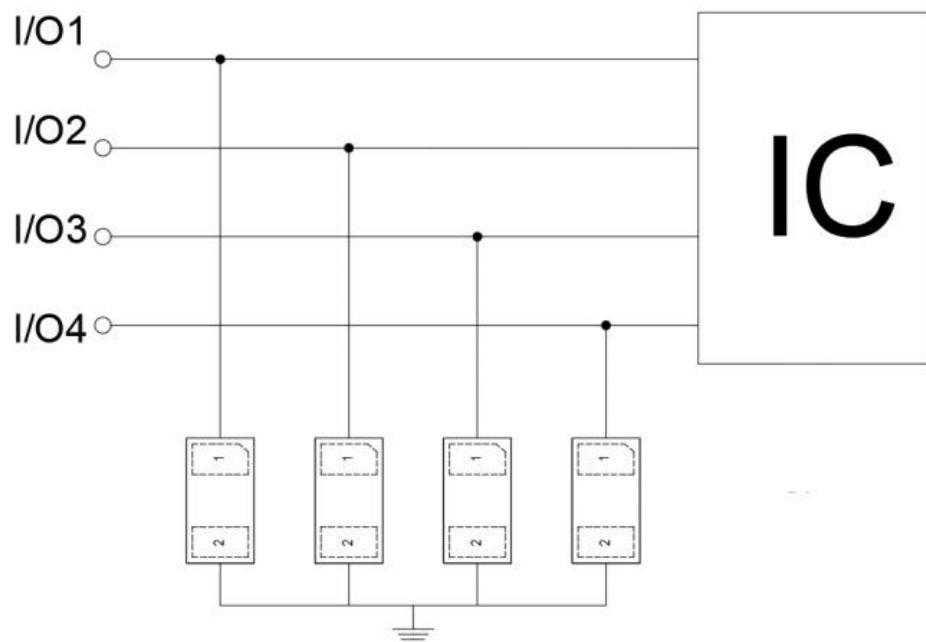
Symbol	Parameters
V _{RWM}	Peak Reverse Working Voltage
I _R	Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
I _F	Forward Current
V _F	Forward Voltage @ I _F



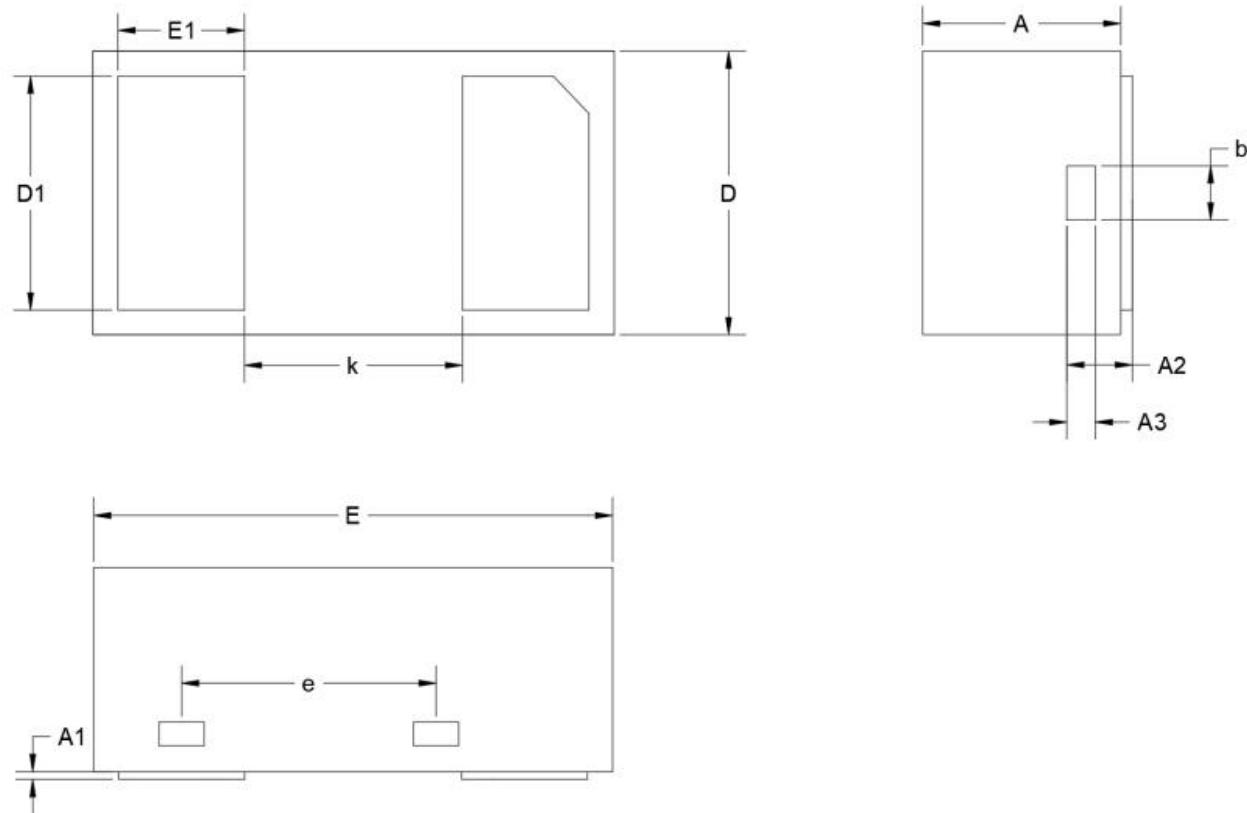
■Typical Characteristic Curve 典型特性曲线



■Typical Applications 典型应用



■ Dimension 外形封装尺寸



Units in millimeters

Symbol	Min.	Nom.	Max.
A	0.350	0.450	0.550
A1	0.000	0.020	0.050
A2	0.077	0.127	0.207
A3	0.013	0.063	0.113
b	0.070	0.120	0.200
D	0.500	0.600	0.700
D1	0.400	0.500	0.600
D2	0.200	0.300	0.400
E	0.900	1.000	1.100
E1	0.150	0.250	0.350
e	0.360	0.410	0.460
k	0.300	0.400	0.500